

SNOA987A-March 2018-Revised January 2019

# High-speed overcurrent detection circuit

# **Design Goal**

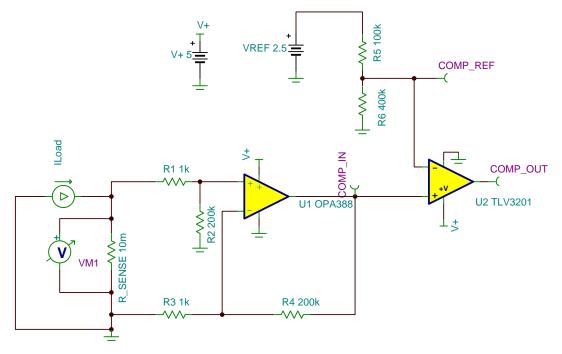
Overcurrent Levels		Supply		Transient Response Time
l <sub>IN</sub> (min)	I <sub>IN</sub> (max)	V+	V–	t
0A	1.0A	5V	0V	< 10µs

# **Design Description**

This high-speed, low-side overcurrent detection solution is implemented with a single zero-drift fast-settling amplifier (OPA388) and one high-speed comparator (TLV3201). This circuit is designed for applications that monitor fast current signals and overcurrent events, such as current detection in motors and power supply units.

The OPA388 is selected for its widest bandwidth with ultra-low offset and fast slew rate. The TLV3201 is selected for its fast response due to its small propagation delay of 40ns and rise time of 4.8ns. This allows the comparator to quickly respond and alert the system of an overcurrent event all within the transient response time requirement. The push-pull output stage also allows the comparator to directly interface with the logic levels of the microcontroller. The TLV3201 also has low power consumption with a quiescent current of  $40\mu$ A.

Typically for low-side current detection, the amplifier across the sense resistor can be used in a noninverting configuration. The application circuit shown, however, uses the OPA388 as a differential amplifier across the sense resistor. This provides a true differential measurement across the shunt resistor and can be beneficial in cases where the supply ground and load ground are not necessarily the same.





#### **Design Notes**

- 1. To minimize errors, choose precision resistors and set  $R_1 = R_3$ , and  $R_2 = R_4$ .
- 2. Select R<sub>SENSE</sub> to minimize the voltage drop across the resistor at the max current of 1 A.
- 3. Due to the ultra-low offset of the OPA388 (0.25  $\mu V$ ), the effect of any offset error from the amplifier is minimal on the mV range measurement across R\_{SENSE}.
- 4. Select the amplifier gain so COMP\_IN reaches 2 V when the system crosses its critical overcurrent value of 1 A.
- 5. Traditional bypass capacitors are omitted to simplify the application circuit.

# **Design Steps**

1. Determine the transfer equation where  $R_1 = R_3$  and  $R_2 = R_4$ .

$$COMP\_IN = \left(R_{SENSE} \cdot I_{LOAD}\right) \cdot \left(\frac{R_2}{R_1 + R_2}\right) \cdot \left(1 + \frac{R_4}{R_3}\right)$$

2. Select the SENSE resistor value assuming a maximum voltage drop of 10 mV with a load current of 1 A in order to minimize the voltage drop across the resistor.

$$R_{\text{SENSE}} = \frac{V_{\text{SENSE}}(\text{max})}{I_{\text{LOAD}}(\text{critical})} = \frac{10\text{mV}}{1\text{A}} = 10\text{m}\Omega$$

3. Select the amplifier gain such that COMP\_IN reaches 2V when the load current reaches the critical threshold of 1A.

$$Gain = \frac{VREF}{R_{SENSE} \cdot I_{LOAD}(critical)} = \frac{2 V}{0.01 V} = \frac{R_2}{R_1 + R_2} \cdot 1 + \frac{R_4}{R_3} = 200$$

Set:

$$R_1 = R_3 = 1k\Omega$$
$$R_2 = R_4 = 200k\Omega$$

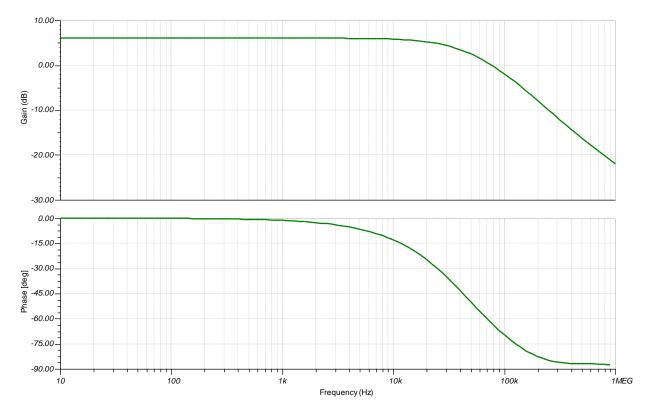
4. Calculate the transimpedance gain of the amplifier in order to verify the following AC simulation results:  $V_{OUT} = I_{LOAD} \cdot 10m \Omega \cdot 200$ 

 $\frac{V_{\text{OUT}}}{I_{\text{LOAD}}} = 10 \text{m}\Omega \cdot 200 = 2$ 

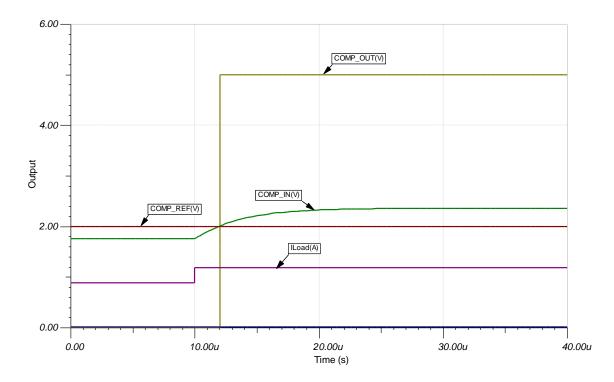




# **COMP\_IN Transimpedance AC Simulation Results**



**Transient Response Simulation Results** 





#### **Design References**

See Analog Engineer's Circuit Cookbooks for TI's comprehensive circuit library.

See the Current sensing using nanopower op amps blog.

# References

- 1. Texas Instruments, Advantages of using nanopower, zero drift amplifiers for battery voltage and current monitoring in portable applications TI tech note
- 2. Texas Instruments, Current sensing in no-neutral light switches TI tech note
- 3. Texas Instruments, GPIO Pins power signal chain in personal electronics running on Li-Ion batteries TI tech note

# **Design Featured Comparator**

TLV3201				
Vs	2.7V to 5.5V			
t <sub>PD</sub>	40ns			
Input V <sub>CM</sub>	Rail-to-rail			
V <sub>os</sub>	1mV			
l <sub>q</sub>	40µA			
TLV3201				

#### **Design Alternate Comparator**

TLV7021				
Vs	1.6V to 5.5V			
t <sub>PD</sub>	260ns			
Input V <sub>CM</sub>	Rail-to-rail			
V <sub>os</sub>	0.5mV			
l <sub>q</sub>	5μΑ			
TLV7021				

# **Design Featured Op Amp**

OPA388				
Vs	2.5V to 5.5V			
Input V <sub>см</sub>	Rail-to-rail			
V <sub>out</sub>	Rail-to-rail			
V <sub>os</sub>	0.25µV			
V <sub>os</sub> Drift	.005µV/°C			
lq	1.7mA/Ch			
I <sub>b</sub>	30pA			
UGBW	10MHz			
OPA388				



# Design Alternate Op Amp

THS4521				
Vs	2.5V to 5.5V			
Input V <sub>CM</sub>	Rail-to-rail			
V <sub>out</sub>	Rail-to-rail			
V <sub>os</sub>	20 µV			
V <sub>os</sub> Drift	μV/°C			
l <sub>q</sub>	1mA/Ch			
I <sub>b</sub>	0.6 µA			
UGBW	145MHz			
THS4521				